

ZVN4210G

#### SOT223 N-CHANNEL ENHANCEMENT MODE VERTICAL DMOS FET

### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(on)</sub>	I <sub>D</sub> T <sub>A</sub> = +25°C
100V	1.5Ω @ V <sub>GS</sub> = 10V	800mA

### **Features and Benefits**

- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

## **Description and Applications**

This MOSFET is designed to minimize the on-state resistance and yet maintain superior switching performance, making it ideal for high efficiency power management applications

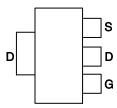
#### **Mechanical Data**

- Package: SOT223 (Type DN)
- Package Material: Molded Plastic, UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.112 grams (Approximate)

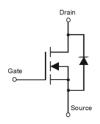
#### SOT223(Type DN)



Top View



Pin Out - Top View



**Equivalent Circuit** 

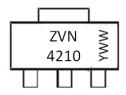
## **Ordering Information** (Note 4)

Port Number	Pookago	Packing		
Part Number	Package	Qty.	Carrier	
ZVN4210GTA	SOT223 (Type DN)	1,000	Tape & Reel	

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

## **Marking Information**



ZVN4210 = Product Type Marking Code YWW = Date Code Marking Y or Y = Year (ex: 1 = 2021) WW or WW = Week (01 to 53)



## Maximum Ratings (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		$V_{DSS}$	100	V
Gate-Source Voltage	$V_{GSS}$	±20	V	
Continuous Drain Current V <sub>GS</sub> = 10V	T <sub>A</sub> = +25°C	Ι <sub>D</sub>	800	mA
Pulsed Drain Current		I <sub>DM</sub>	6	А

# Thermal Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation	$T_A = +25^{\circ}C$	$P_{D}$	2	W
Operating and Storage Temperature Range	$T_{J_1}T_{STG}$	-55 to +150	°C	

# Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

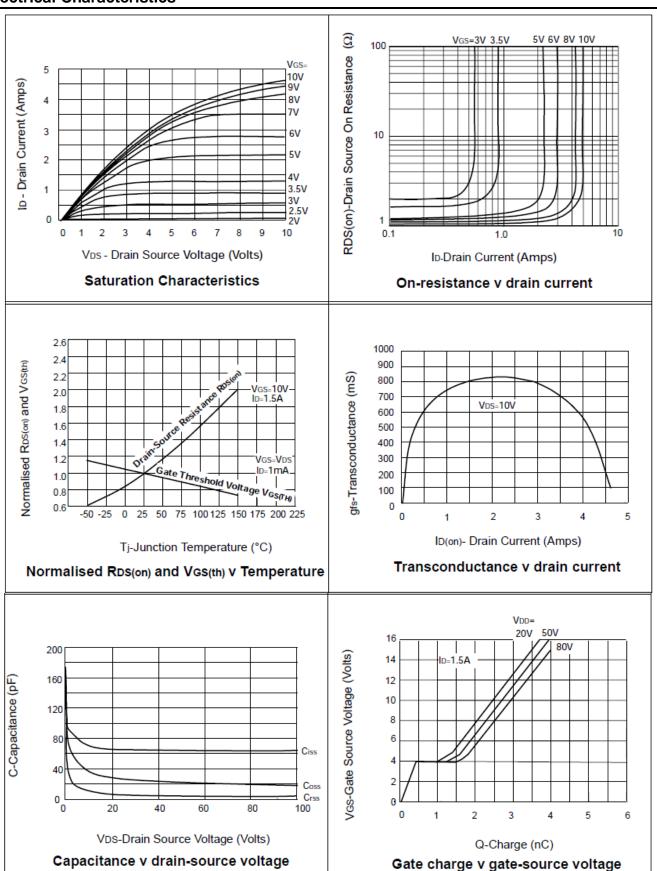
Characteristic	Cumbal	Min	Tim	May	I In:i4	Test Condition	
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS		1					
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	100	-	_	V	$V_{GS} = 0V, I_D = 1mA$	
Zoro Coto Voltogo Droin Current	la a a	_	-	10	μΑ	$V_{DS} = 100V, V_{GS} = 0V$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	-	-	100	μΑ	V <sub>DS</sub> =80V, V <sub>GS</sub> =0V, T=125°C (Note 6)	
Gate-Source Leakage	I <sub>GSS</sub>	-	_	±100	nA	$V_{GS} = \pm 20V$ , $V_{DS} = 0V$	
ON CHARACTERISTICS							
Gate Threshold Voltage	V <sub>GS(th)</sub>	0.8	-	2.4	V	$V_{DS} = V_{GS}$ , $I_D = 1mA$	
Otatia Basia Ossana Os Basiatana		-	-	1.5	Ω	$V_{GS} = 10V, I_D = 1.5A$	
Static Drain-Source On-Resistance	R <sub>DS(on)</sub>	-	-	1.8	Ω	$V_{GS} = 5V, I_D = 0.5A$	
Diada Farmand Vallana (Nata 5)		=	0.79	_		I <sub>S</sub> =0.32A, V <sub>GS</sub> =0V	
Diode Forward Voltage (Note 5)	V <sub>SD</sub>	-	0.89	_	V	I <sub>S</sub> =1.0A, V <sub>GS</sub> =0V	
On-State Drain Current (Note 5)	I <sub>D(on)</sub>	2.5	-	-	Α	V <sub>DS</sub> =25V, V <sub>GS</sub> =10V	
Forward Transconductance (Notes 5, 6)	<b>g</b> fs	250	-	-	mS	$V_{DS} = 25V, I_{D} = 1.5A$	
Reverse Recovery Time (to I <sub>R</sub> =10%)	t <sub>RR</sub>	-	135	_	ns	$I_F = 0.45A$ , $V_{GS} = 0V$ , $I_R = 100mA$ , $V_R = 10V$	
DYNAMIC CHARACTERISTICS (Note 6)							
Input Capacitance	C <sub>iss</sub>	_	_	100	pF		
Output Capacitance	Coss	_	_	40	pF	$V_{DS} = 25V, V_{GS} = 0V, f = 1MHz$	
Reverse Transfer Capacitance	C <sub>rss</sub>	_	_	12	pF		
Turn-On Delay Time (Note 7)	t <sub>D(on)</sub>	_	_	4	ns		
Turn-On Rise Time (Note 7)	t <sub>R</sub>	-	-	8	ns	), OE), 1 4 54	
Turn-Off Delay Time (Note 7)	t <sub>D(off)</sub>	-	-	20	ns	$V_{DD} = 25V, I_{D} = 1.5A$	
Turn-Off Fall Time (Note 7)	t <sub>F</sub>	_	-	30	ns	]	

Notes:

- 5. Measured under pulsed conditions. Width=300 $\mu$ s. Duty cycle  $\leq$  2%.
- 6. Sample test.
  7. Switching times measured with 50Ω source impedance and <5ns rise time on a pulse generator. Spice parameter data is available upon request for this



### **Electrical Characteristics**

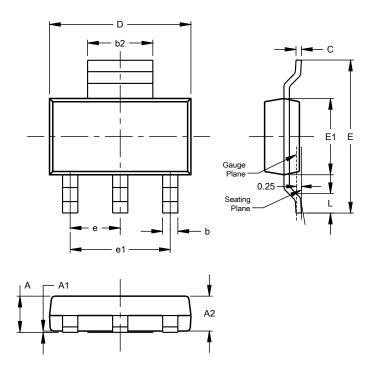




# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT223 (Type DN)

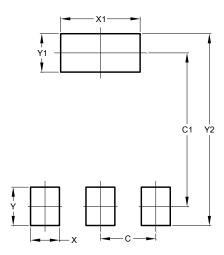


SOT223 (Type DN)				
Dim	Min	Max	Тур	
Α		1.70		
A1	0.01	0.15		
A2	1.50	1.68	1.60	
b	0.60	0.80	0.70	
b2	2.90	3.10		
С	0.20	0.32		
D	6.30	6.70		
Е	6.70	7.30		
E1	3.30	3.70		
е			2.30	
e1			4.60	
L	0.85			
All Dimensions in mm				

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### SOT223 (Type DN)



•			
Dimensions	Value (in mm)		
С	2.30		
C1	6.40		
Х	1.20		
X1	3.30		
Y	1.60		
Y1	1.60		
Y2	8.00		



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